TOSHIBA Photocoupler GaAlAs IRED + Photo IC

TLP701

Industrial inverters Inverter for air conditioners IGBT/Power MOS FET gate drive

TLP701 consists of a GaAlAs light-emitting diode and an integrated photodetector.

This unit is 6-lead SDIP package. The TLP701 is 50% smaller than the 8-pin DIP and meets the reinforced insulation class requirements of international safety standards. Therefore the mounting area can be reduced in equipment requiring safety standard certification.

The TLP701 is suitable for gate driving circuits for IGBTs or power MOSFETs. In particular, the TLP701 is capable of "direct" gate driving of low-power IGBTs.

- Peak output current : ±0.6 A (max)
- Guaranteed performance over temperature : -40 to 100°C
- Supply current
- Power supply voltage
- Threshold input current
- Switching time (tpLH / tpHL)
- Common mode transient immunity
- Isolation voltage
- Construction mechanical rating

	7.62-mm pitch standard type	10.16-mm pitch TLPXXXF type
Creepage Distance	7.0 mm (min)	8.0 mm (min)
Clearance	7.0 mm (min)	8.0 mm (min)
Insulation Thickness	0.4 mm (min)	0.4 mm (min)

- **UL Recognized**
 - Option (D4)

TÜV approved

: EN60747-5-2 Certificate No. R50033433

: UL1577, File No. E67349

: 2 mA (max)

: 700 ns (max)

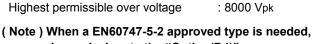
: ±10 kV/µs (min)

: 5000 Vrms (min)

 $: I_{FLH} = 5 \text{ mA} (\text{max})$

: 10 to 30 V

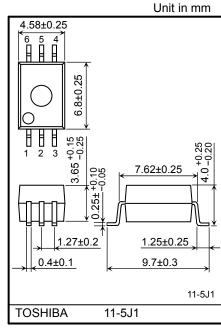
Maximum operating insulation voltage : 890 Vpk Highest permissible over voltage



please designate the "Option(D4)"

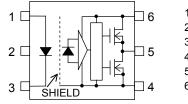
Truth Table

Input	LED	Tr1	Tr2	Output
Н	ON	ON	OFF	Н
L	OFF	OFF	ON	L

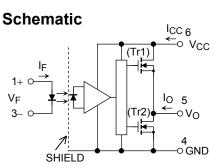


Weight: 0.26 g (typ.)

Pin Configuration (Top View)



1: ANODE 2: NC 3: CATHODE 4: GND 5: VO (OUTPUT) 6: V_{CC}



A 0.1-µF bypass capacitor must be connected between pins 6 and 4. (See Note 6.)

Absolute Maximum Ratings (Ta = 25 °C)

	Characteristics	Symbol	Rating	Unit	
	Forward current			20	mA
	Forward current derating (Ta ≥ 85°C)		∆I _F /∆Ta	-0.54	mA/°C
LED	Peak transient forward current	(Note 1)	I _{FP}	1	А
	Reverse voltage		V _R	5	V
	Junction temperature		Тј	125	°C
	"H" peak output current	(Note 2)	I _{OPH}	-0.6	А
ď	ъ "L" peak output current	(Note 2)	IOPL	0.6	А
Detector	Output voltage		VO	35	V
ă	Supply voltage		V _{CC}	35	V
	Junction temperature		Тј	125	°C
Oper	rating frequency	(Note 3)	f	25	kHz
Oper	Operating temperature range		T _{opr}	-40 to 100	°C
Stora	Storage temperature range		T _{stg}	-55 to 125	°C
Lead	Lead soldering temperature (10 s) (Note 4)		T _{sol}	260	°C
Isola	tion voltage (AC, 1 minute, R.H. ≤ 60%)	(Note 5)	BVS	5000	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

- Note 1: Pulse width $P_W \le 1 \mu s$, 300 pps
- Note 2: Exponential waveform pulse width $P_W \le 2 \mu s$, f $\le 15 \text{ kHz}$
- Note 3: Exponential waveform $I_{OPH} \leq -0.3 \text{ A} (\leq 2 \text{ }\mu\text{s}), I_{OPL} \leq +0.3 \text{ A} (\leq 2 \text{ }\mu\text{s}), Ta = 100 \text{ }^{\circ}\text{C}$
- Note 4: For the effective lead soldering area
- Note 5: Device considered a two-terminal device: pins 1, 2 and 3 paired with pins 4, 5 and 6 respectively.
- Note 6: A ceramic capacitor (0.1 μF) should be connected from pin 6 to pin 4 to stabilize the operation of the high gain linear amplifier. Failure to provide the bypassing may impair the switching property. The total lead length between capacitor and coupler should not exceed 1 cm.

Recommended Operating Conditions

Characteristics		Symbol	Min	Тур.	Max	Unit
Input current, ON	(Note 7)	I _{F (ON)}	7.5	_	10	mA
Input voltage, OFF		V _{F (OFF)}	0	_	0.8	V
Supply voltage		V _{CC}	10	_	30	V
Peak output current		I _{OPH} / I _{OPL}	_	_	± 0.2	А
Operating temperature		T _{opr}	-40		100	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Note 7: Input signal rise time (fall time) < 0.5 μ s.

Electrical Characteristics (Ta = -40 to 100 °C, unless otherwise specified)

Characteristics		Symbol	Test Circuit	Test Condition		Min	Typ.*	Max	Unit
Forward voltage		VF	_	I _F = 5 mA, Ta = 25 °C		_	1.55	1.70	V
Temperature coefficient of forward voltage		∆V _F /∆Ta	_	$I_F = 5 \text{ mA}$		_	-2.0	_	mV/°C
Input reverse current		I _R	_	V _R = 5 V, Ta = 25	°C	_	—	10	μA
Input capacitance		CT	_	V =0 V, f = 1 MHz	, Ta = 25 °C	_	45	—	pF
	"H" Level	I _{OPH1}	1	V _{CC} = 15 V	$V_{6-5} = 4 V$	-0.2	-0.38	—	A
Output current (Note 8)	H Level	I _{OPH2}	1	I _F = 5 mA	V ₆₋₅ = 10 V	-0.4	-0.60	_	
	"L" Level	I _{OPL1}	2	V _{CC} = 15 V I _F = 0 mA	V5-4 = 2 V	0.2	0.36	_	
		I _{OPL2}	2		V5-4 = 10 V	0.4	0.62	_	
	"H" Level	V _{OH}	3	V _{CC} = 10 V	$I_O = -100 \text{ mA},$ $I_F = 5 \text{ mA}$	6.0	8.5	_	v
Output voltage	"L" Level	V _{OL}	4		I _O = 100 mA, V _F = 0.8 V	_	0.4	1.0	
Curral v averaget	"H" Level	I _{CCH}	5	V _{CC} = 10 to 30 V	I _F = 10 mA		1.4	2.0	
Supply current	"L" Level	ICCL	6	V _O =Open	I _F = 0 mA	—	1.3	2.0	mA
Threshold input current	$L\toH$	IFLH	_	– V _{CC} = 15 V, V _O > 1 V		—	2.5	5	mA
Threshold input voltage	$H\toL$	V _{FHL}	_	V _{CC} = 15 V, V _O < 1 V		0.8	_	_	V
Supply voltage		V _{CC}	—	_		10	—	30	V

(*): All typical values are at Ta = $25^{\circ}C$

Note 8: Duration of lo time \leq 50 µs, 1 pulse

Note 9: This product is more sensitive than conventional products to electrostatic discharge (ESD) owing to its low power consumption design. It is therefore all the more necessary to observe general precautions regarding ESD when handling this component.

Isolation Characteristics (Ta = 25 °C)

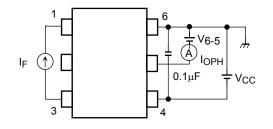
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Capacitance input to output	CS	V = 0 V , f = 1MHz (Note 5)	_	1.0		pF
Isolation resistance	R _S	R.H. ≤ 60 %, V _S = 500 V (Note 5)	1×10 ¹²	10 ¹⁴	_	Ω
		AC, 1 minute	5000		_	Vrms
Isolation voltage	BVS	AC, 1 second, in oil	_	10000	_	VIIIS
		DC, 1 minute, in oil	_	10000		Vdc

Switching Characteristics (Ta = -40 to 100 °C, unless otherwise specified)

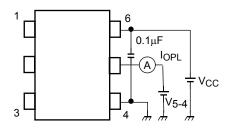
Characteristics		Symbol	Test Circuit	Test Condition		Min	Тур.*	Max	Unit
Propagation delay time	$L\toH$	^t pLH	-	V _{CC} = 30 V	$I_F=0\rightarrow 5~mA$	100	_	700	
	$H \to L$	^t pHL			$I_F = 5 \rightarrow 0 \text{ mA}$	100	_	700	
Output rise time (10–90 %)		tr	7	$R_g = 47 \Omega$ $C_g = 3 nF$	$I_F = 0 \rightarrow 5 \text{ mA}$	_	50	_	ns
Output fall time (90–10 %)		tf			$I_F=5\rightarrow 0~mA$		50		
Switching time dispersion between ON and OFF		tpHL-tpLH			I _F = 0 , 5 mA	-500		500	
Common mode transient i at HIGH level output	mmunity	CM _H	8	V _{CM} =1000 Vp-p	$I_F = 5 \text{ mA}$ $V_O \text{ (min)} = 26 \text{ V}$	-10000	_	_	- V/μs
Common mode transient immunity at LOW level output		CML	0	V _{CC} = 30 V Ta = 25 °C	I _F = 0 mA V _{O (max)} = 1 V	10000	_	_	v/μs

(*): All typical values are at Ta = 25 °C.

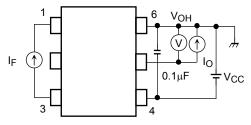
Test Circuit 1: IOPH



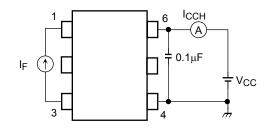
Test Circuit 2: IOPL

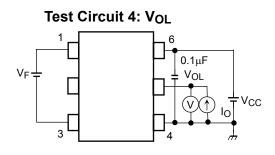


Test Circuit 3: VOH

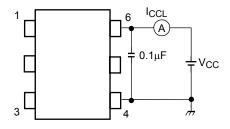


Test Circuit 5: ICCH

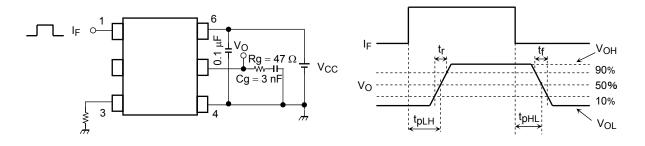




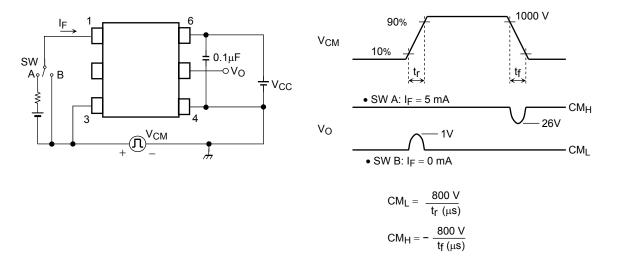
Test Circuit 6: ICCL



Test Circuit 7: tpLH, tpHL, tr, tf, PDD



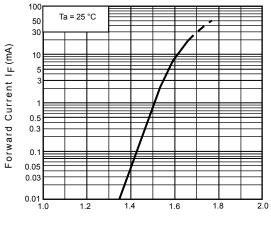
Test Circuit 8: CM_H, CM_L



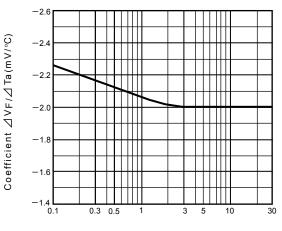
 CM_L (CM_H) is the maximum rate of rise (fall) of the common mode voltage that can be sustained with the output voltage in the LOW (HIGH) state.



⊿VF/⊿Ta-IF







Forward Current I_F (mA)

I_{FLH} – Ta

5

3

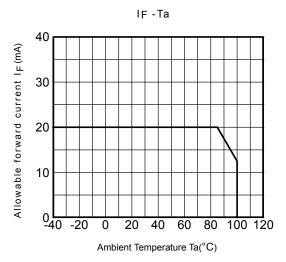
1

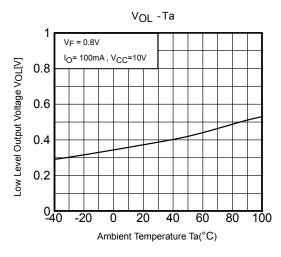
(mA) 4

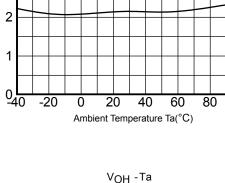
Threshold input current IFLH

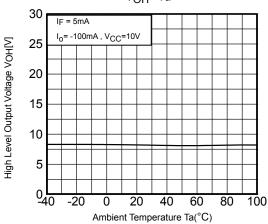
VCC=15V

VO>1V









*: The above graphs show typical characteristics.

100

40

60

V8-6=4.0V

V8-6=10V

60

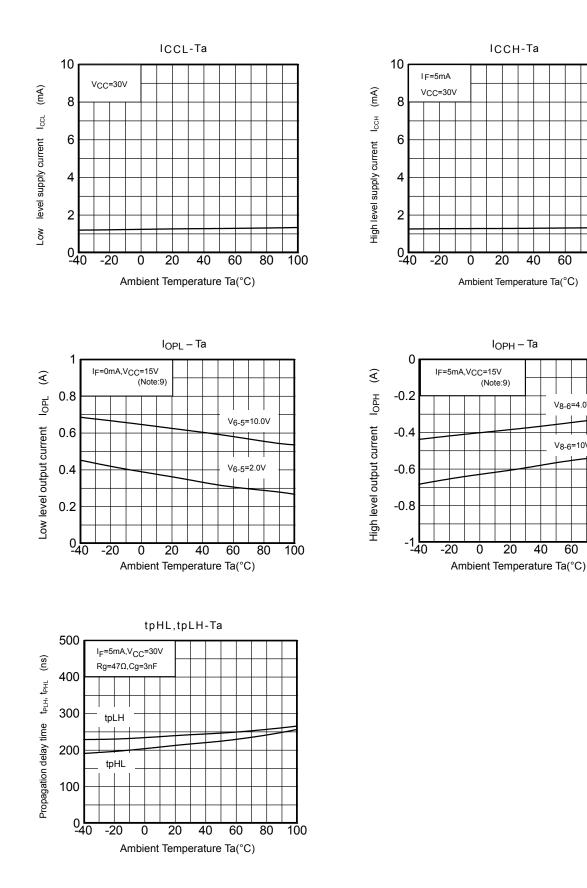
40

80

100

80

100



*: The above graphs show typical characteristics.

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20070701-EN

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